BC237, BC237B, BC237C, BC239C

Amplifier Transistors NPN Silicon

Features

• Pb–Free Packages are Available*

MAXIMUM RATINGS

Rating		Symbol	Value	Unit
Collector – Emitter Voltage	BC237 BC239	V _{CEO}	45 25	Vdc
Collector – Emitter Voltage	BC237 BC239	V _{CES}	50 30	Vdc
Collector – Emitter Voltage	BC237 BC239	V _{EBO}	6.0 5.0	Vdc
Collector Current – Continuous		۱ _C	100	mAdc
Total Power Dissipation @ $T_A = 25^{\circ}C$ Derate above $T_A = 25^{\circ}C$		P _D	350 2.8	mW mW/°C
Total Power Dissipation @ $T_A = 25^{\circ}C$ Derate above $T_A = 25^{\circ}C$		PD	1.0 8.0	W mW/°C
Operating and Storage Tempera Range	ature	T _J , T _{stg}	-55 to +150	°C

THERMAL CHARACTERISTICS

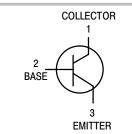
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	R_{\thetaJA}	357	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	125	°C/W

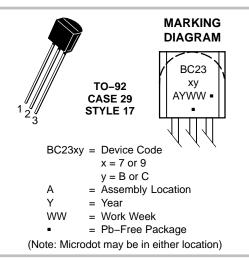
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



ON Semiconductor®







ORDERING INFORMATION

Device	Package	Shipping [†]				
BC237	TO-92	5000 Units / Bulk				
BC237G	TO–92 (Pb–Free)	5000 Units / Bulk				
BC237B	TO-92	5000 Units / Bulk				
BC237BG	TO–92 (Pb–Free)	5000 Units / Bulk				
BC237BRL1	TO-92	2000/Tape & Reel				
BC237BRL1G	TO–92 (Pb–Free)	2000/Tape & Reel				
BC237BZL1	TO-92	2000/Ammo Pack				
BC237BZL1G	TO–92 (Pb–Free)	2000/Ammo Pack				
BC237C	TO-92	5000 Units / Bulk				
BC237CG	TO–92 (Pb–Free)	5000 Units / Bulk				

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

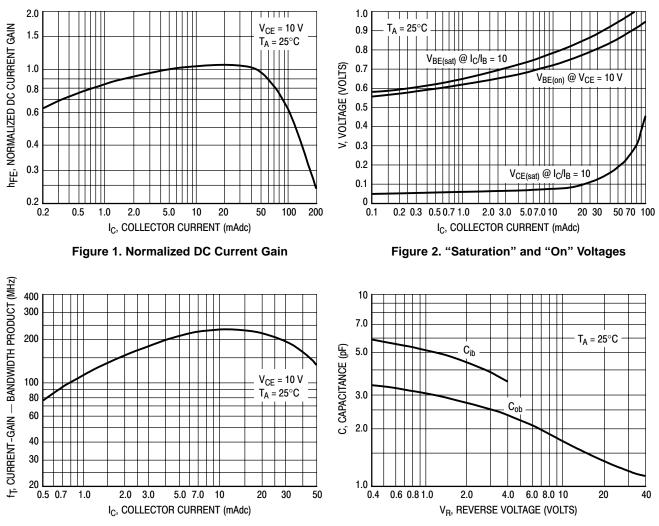
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

BC237, BC237B, BC237C, BC239C

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS				•		
Collector – Emitter Breakdown Voltage $(I_C = 2.0 \text{ mA}, I_B = 0)$	BC237 BC239	V _{(BR)CEO}	45 25		-	V
Emitter – Base Breakdown Voltage $(I_E = 100 \ \mu A, I_C = 0)$	BC237 BC239	V _{(BR)EBO}	6.0 5.0			V
	BC239 BC237 BC239 BC237	I _{CES}	- - - -	0.2 0.2 0.2 0.2	15 15 4.0 4.0	nA μA
ON CHARACTERISTICS	I		1		1	1
DC Current Gain ($I_C = 10 \ \mu\text{A}, \ V_{CE} = 5.0 \ \text{V}$) ($I_C = 2.0 \ \text{mA}, \ V_{CE} = 5.0 \ \text{V}$) ($I_C = 100 \ \text{mA}, \ V_{CE} = 5.0 \ \text{V}$)	BC237B BC237C/239C BC237 BC237B BC237C/239C BC237C/239C BC237C/239C	h _{FE}	- 120 200 380 -	150 270 - 290 500 180 300	- 800 460 800 -	_
Collector – Emitter On Voltage ($I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA}$) ($I_C = 100 \text{ mA}, I_B = 5.0 \text{ mA}$)	BC237/BC239 BC237/BC239	V _{CE(sat)}		0.07 0.2	0.2 0.6	V
$\begin{array}{l} \text{Base}-\text{Emitter Saturation Voltage} \\ (I_{C}=10 \text{ mA}, I_{B}=0.5 \text{ mA}) \\ (I_{C}=100 \text{ mA}, I_{B}=5.0 \text{ mA}) \end{array}$		V _{BE(sat)}		0.6	0.83 1.05	V
$\begin{array}{l} \text{Base-Emitter On Voltage} \\ (I_{C} = 100 \ \mu\text{A}, \ V_{CE} = 5.0 \ \text{V}) \\ (I_{C} = 2.0 \ \text{mA}, \ V_{CE} = 5.0 \ \text{V}) \\ (I_{C} = 100 \ \text{mA}, \ V_{CE} = 5.0 \ \text{V}) \end{array}$		V _{BE(on)}	 0.55 	0.5 0.62 0.83	_ 0.7 _	V
DYNAMIC CHARACTERISTICS						
Current-Gain — Bandwidth Product ($I_C = 0.5 \text{ mA}, V_{CE} = 3.0 \text{ V}, f = 100 \text{ MHz}$) ($I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}, f = 100 \text{ MHz}$)	BC237 BC239 BC237 BC239	f _T	- - 150 150	100 140 200 280	- - - -	MHz
Collector–Base Capacitance ($V_{CB} = 10 \text{ V}, I_{C} = 0, f = 1.0 \text{ MHz}$)		C _{obo}	-	-	4.5	pF
Emitter-Base Capacitance ($V_{EB} = 0.5 V$, $I_C = 0$, $f = 1.0 MHz$)		C _{ibo}	-	8.0	-	pF
Noise Figure ($I_C = 0.2 \text{ mA}, V_{CE} = 5.0 \text{ V}, R_S = 2.0 \text{ k}\Omega, f = 1.0 \text{ kHz}$) ($I_C = 0.2 \text{ mA}, V_{CE} = 5.0 \text{ V}, R_S = 2.0 \text{ k}\Omega, f = 1.0 \text{ kHz}$, 2	BC239 Af = 200 Hz) BC237 BC239	NF	- - -	2.0 2.0 2.0	4.0 10 4.0	dB

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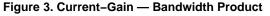


Figure 4. Capacitances

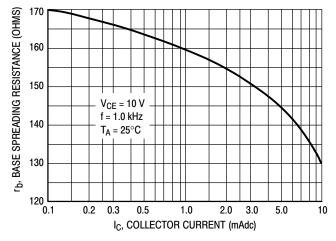
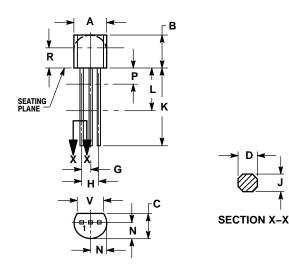


Figure 5. Base Spreading Resistance

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PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 **ISSUE AL**



NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.

2.

BEYOND DIMENSION K MINIMUM.

CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED. 3. LEAD DIMENSION IS UNCONTROLLED IN P AND

	INCHES		MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.175	0.205	4.45	5.20	
В	0.170	0.210	4.32	5.33	
С	0.125	0.165	3.18	4.19	
D	0.016	0.021	0.407	0.533	
G	0.045	0.055	1.15	1.39	
Н	0.095	0.105	2.42	2.66	
J	0.015	0.020	0.39	0.50	
Κ	0.500		12.70		
L	0.250		6.35		
Ν	0.080	0.105	2.04	2.66	
Р		0.100		2.54	
R	0.115		2.93		
V	0.135		3.43		

STYLE 17:

PIN 1. COLLECTOR BASE 2.

3. EMITTER

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